

# THD215HI

# HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- U.L. RECOGNISED ISOWATT218 PACKAGE (U.L. FILE # E81734 (N)).

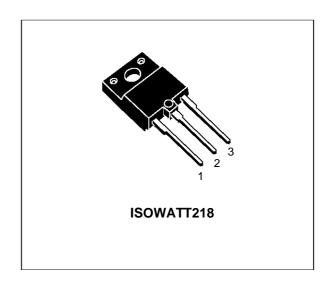
#### **APPLICATIONS**

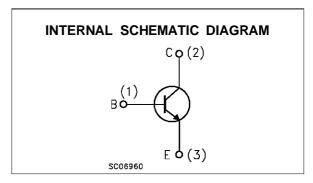
 HORIZONTAL DEFLECTION FOR COLOUR TV AND MONITORS

#### **DESCRIPTION**

This device is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.

The THD series is designed for use in horizontal deflection circuits in televisions and monitors.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage (I <sub>E</sub> = 0)	1500	V
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)	700	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	10	V
Ic	Collector Current	8	Α
Ісм	Collector Peak Current (tp < 5 ms)	12	Α
lΒ	Base Current	5	Α
I <sub>BM</sub>	Base Peak Current (t <sub>p</sub> < 5 ms)	8	Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> = 25 °C	57	W
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

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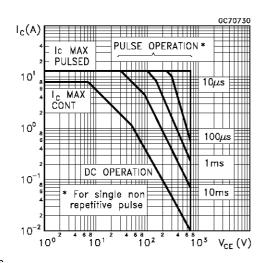
#### THERMAL DATA

# **ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25$ $^{\circ}C$ unless otherwise specified)

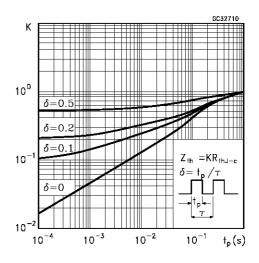
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 1500 V V <sub>CE</sub> = 1500 V			0.2 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			100	μΑ
V <sub>CEO(sus)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 100 mA	700			V
V <sub>CE(sat)*</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 6 A I <sub>B</sub> = 1.2 A			1.3	V
V <sub>BE(sat)*</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 6 A I <sub>B</sub> = 1.2 A			1.3	V
h <sub>FE</sub> *	DC Current Gain	$I_{C} = 6 \text{ A}$ $V_{CE} = 5 \text{ V}$ $I_{C} = 6 \text{ A}$ $V_{CE} = 5 \text{ V}$ $T_{j} = 125 ^{\circ}\text{C}$	6 4		12	
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time			3.3 160		μs ns

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

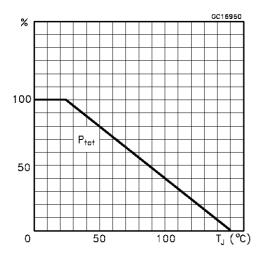
## Safe Operating Area



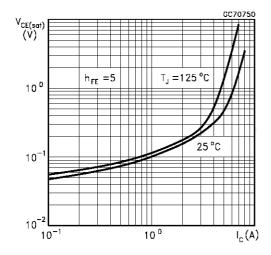
## Thermal Impedance



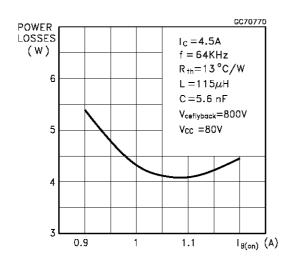
#### **Derating Curve**



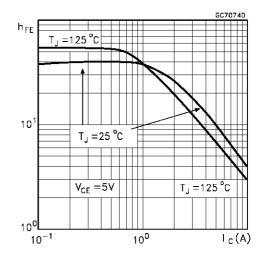
## Collector Emitter Saturation Voltage



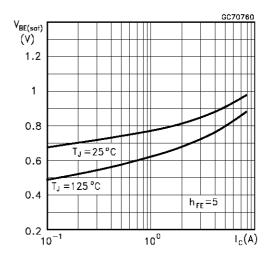
#### Power Losses at 64 KHz



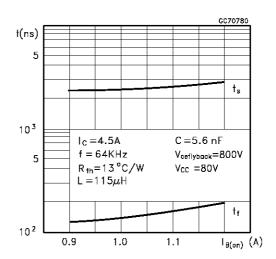
### DC Current Gain



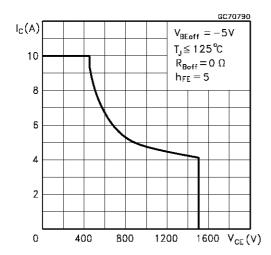
Base Emitter Saturation Voltage



Switching Time Inductive Load at 64 KHz

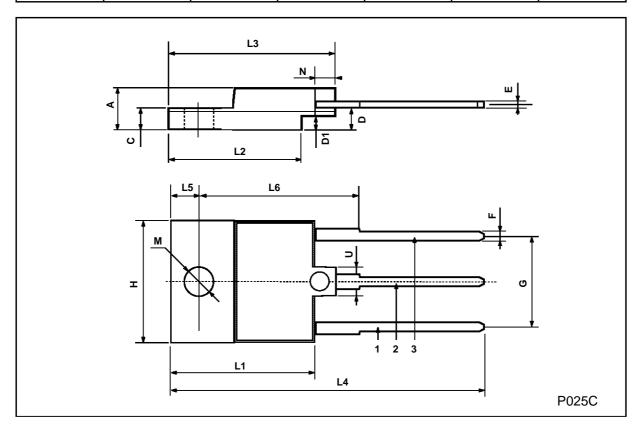


### Reverse Biased SOA



# **ISOWATT218 MECHANICAL DATA**

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	5.35		5.65	0.210		0.222
С	3.3		3.8	0.130		0.149
D	2.9		3.1	0.114		0.122
D1	1.88		2.08	0.074		0.081
Е	0.75		1	0.029		0.039
F	1.05		1.25	0.041		0.049
G	10.8		11.2	0.425		0.441
Н	15.8		16.2	0.622		0.637
L1	20.8		21.2	0.818		0.834
L2	19.1		19.9	0.752		0.783
L3	22.8		23.6	0.897		0.929
L4	40.5		42.5	1.594		1.673
L5	4.85		5.25	0.190		0.206
L6	20.25		20.75	0.797		0.817
М	3.5		3.7	0.137		0.145
N	2.1		2.3	0.082		0.090
U		4.6			0.181	



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